10 V Precision Voltage Reference

REF01

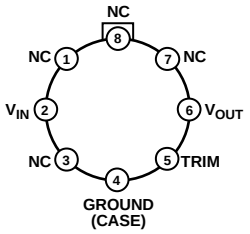
FEATURES

10 V output, ±0.3% maximum
Adjustment range, ±3% minimum
Excellent temperature stability, 8.5 ppm/°C maximum
Low noise, 30 µV p-p maximum
Low supply current, 1.4 mA maximum
Wide input voltage range, 12 V to 40 V
High load driving capability, 10 mA
No external components
Short-circuit proof

GENERAL DESCRIPTION

The REF01 precision voltage reference provides a stable 10 V output that can be adjusted over a 3% range with minimal effect on temperature stability. Single-supply operation over an input voltage range of 12 V to 40 V, a low current drain of 1 mA, and excellent temperature stability are achieved with an improved band gap design. Low cost, low noise, and low power make the REF01 an excellent choice whenever a stable voltage reference is required. Applications include DACs and ADCs, portable instrumentation, and digital voltmeters. Full military temperature range devices with screening to MIL-STD-883 are available. For new designs, refer to ADR01.

PIN CONFIGURATIONS



NC = NO CONNECT. DO NOT CONNECT ANYTHING ON THESE PINS. SOME OF THEM ARE RESERVED FOR FACTORY TESTING PURPOSES.

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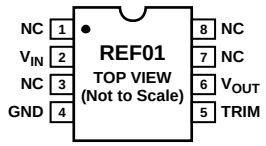
Figure 1. TO-99 (J Suffix)



NC = NO CONNECT. DO NOT CONNECT ANYTHING ON THESE PINS. SOME OF THEM ARE RESERVED FOR FACTORY TESTING PURPOSES.

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Figure 2. 8-Lead PDIP (P-Suffix)
8-Lead CERDIP (Z-Suffix)
8-Lead SOIC (S-Suffix)

OUTPUT RESISTORS

REF01 OPTION	R9	R11	R12
P AND S PACKAGES	18kΩ	4.5kΩ	33.3kΩ
J AND Z PACKAGES, AND 883C PRODUCT	50kΩ	2kΩ	16.7kΩ

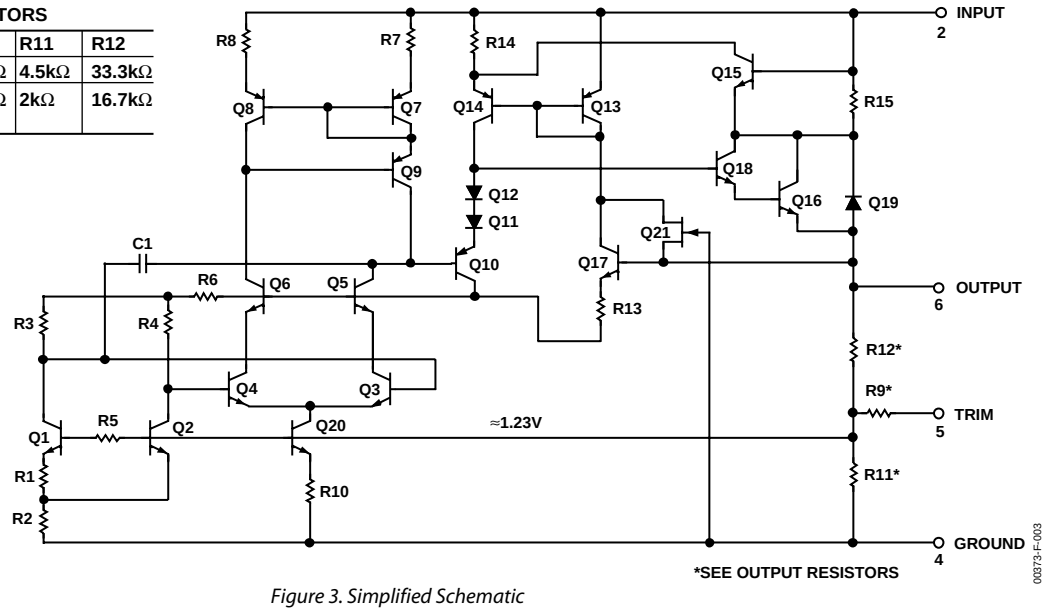

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Figure 3. Simplified Schematic

SPECIFICATIONS

ELECTRICAL SPECIFICATIONS

@ V_{IN} = 15 V, T_A = 25°C, unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	REF01A/REF01E			REF01H			Unit
			Min	Typ	Max	Min	Typ	Max	
Output Voltage	V_O	I_L = 0 mA	9.97	10.00	10.03	9.95	10.00	10.05	V
Output Adjustment Range	ΔV_{TRIM}	R_P = 10 kΩ	±3.0	±3.3		±3.0	±3.3		%
Output Voltage Noise[1]									
S, Z, P Packages	$e_{n\ p\text{-}p}$	0.1 Hz to 10 Hz		30			30		µV p-p
J, 883 Parts	$e_{n\ p\text{-}p}$	0.1 Hz to 10 Hz		35			35		µV p-p
Line Regulation[2]		V_{IN} = 13 V to 33 V		0.006	0.010		0.006	0.010	%/V
Load Regulation[2]		I_L = 0 mA to 10 mA		0.005	0.008		0.006	0.010	%/mA
Turn-On Settling Time[3]	t_{ON}	To ± 0.1% of final value		5			5		µs
Quiescent Supply Current	I_{SY}	No load		1.0	1.4		1.0	1.4	mA
Load Current	I_L		10			10			mA
Sink Current[4]	I_S		−0.3	−0.5		−0.3	−0.5		mA
Short-Circuit Current	I_{SC}	V_O = 0		30			30		mA

[1] Sample tested.
[2] Line and load regulation specifications include the effect of self-heating.
[3] Guaranteed by design, not production tested.
[4] During sink current test, the device meets the output voltage specified.

@ V_{IN} = 15 V, −55°C ≤ T_A ≤ +125°C for REF01A/REF01E, and 0°C ≤ T_A ≤ 70°C for REF01H, and I_L = 0 mA, unless otherwise noted.

Table 2.

Parameter	Symbol	Conditions	REF01A/REF01E			REF01H			Unit
			Min	Typ	Max	Min	Typ	Max	
Output Voltage Change	ΔV_{OT}	0°C ≤ T_A ≤ 70°C		0.02	0.06		0.07	0.17	%
with Temperature[1, 2]		−55°C ≤ T_A ≤+ 125°C		0.06	0.15		0.18	0.45	%
Output Voltage	TCV_O			3.0	8.5		10.0	25.0	ppm/°C
Temperature Coefficient[3]									
Change in V_O Temperature Coefficient		R_P = 10 kΩ		0.7			0.7		ppm/%
with Output Adjustment									
Line Regulation		0°C ≤ T_A ≤ 70°C		0.007	0.012		0.007	0.012	%/V
(V_{IN} = 13 V to 33 V)[4]		−55°C ≤ T_A ≤ + 125°C		0.009	0.015		0.009	0.015	%/V
Load Regulation		0°C ≤ T_A ≤ 70°C		0.006	0.010		0.007	0.012	%/mA
(I_L = 0 mA to 8 mA)[4]		−55°C ≤ T_A ≤ + 125°C		0.007	0.012		0.009	0.015	%/mA

[1] ΔV_{OT} is defined as the absolute difference between the maximum output voltage and the minimum output voltage over the specified temperature range expressed as a percentage of 10 V:

$$\Delta V_{OT} = \left| \frac{V_{MAX} - V_{MIN}}{10\ \text{V}} \right| \times 100$$

[2] ΔV_{OT} specification applies trimmed to 10000 V or untrimmed.
[3] TCV_O is defined as ΔVar divided by the temperature range; therefore,

$$TCV_O(0°\text{C}\ to + 70°\text{C}) = \frac{\Delta V_{OT}(0°\text{C}\ to + 70°\text{C})}{70°\text{C}} \text{ and } TCV_O(-55°\text{C}\ to + 125°\text{C}) = \frac{\Delta V_{OT}(-55°\text{C}\ to + 125°\text{C})}{180°\text{C}}$$

[4] Line and load regulation specifications include the effect of self-heating.

@ V_{IN} = 15 V, T_A = 25°C, unless otherwise noted.

Table 3.

Parameter	Symbol	Conditions	REF01C Min	REF01C Typ	REF01C Max	Unit
Output Voltage	V_O	I_L = 0 mA	9.90	10.00	10.10	V
Output Adjustment Range	ΔV_{TRIM}	R_P = 10 kΩ	±2.7	±3.3		%
Output Voltage Noise[1]						
S, Z, P Packages	$e_{n\ p\text{-}p}$	0.1 Hz to 10 Hz		30		µV p-p
J, 883 Parts	$e_{n\ p\text{-}p}$	0.1 Hz to 10 Hz		35		µV p-p
Line Regulation[2]		V_{IN} = 13 V to 33 V		0.009	0.015	%/V
Load Regulation[2]		I_L = 0 mA to 8 mA		0.006	0.015	%/mA
Turn-On Settling Time[3]	t_{ON}	To ±0.1% of final value		5		µs
Quiescent Supply Current	I_{SY}	No load		1.0	1.6	mA
Load Current	I_L		8			mA
Sink Current[4]	I_S		−0.3	−0.5		mA
Short-Circuit Current	I_{SC}	V_O = 0		30		mA

[1] Sample tested.
[2] Line and load regulation specifications include the effect of self-heating.
[3] Guaranteed by design, not production tested.
[4] During sink current test, the device meets the output voltage specified.

@ V_{IN} = 15 V, 0°C ≤ T_A ≤ +70°C for REF01CJ, REF01CZ, and −40°C ≤ T_A ≤ +85°C for REF01CP and REF01CS, unless otherwise noted.

Table 4.

Parameter	Symbol	Conditions	REF01C Min	REF01C Typ	REF01C Max	Unit
Output Voltage Change with Temperature[1, 2]	ΔV_{OT}			0.14	0.45	%
Output Voltage Temperature Coefficient[3]	TCV_O			20	65	ppm/°C
Change in V_O Temperature Coefficient with Output Adjustment		R_P = 10 kΩ		0.7		ppm/°C
Line Regulation[4]		V_{IN} =13 V to 30 V		0.011	0.018	%/V
Load Regulation[4]		I_L = 0 to 5 mV		0.008	0.018	%/mA

[1] ΔV_{OT} is defined as the absolute difference between the maximum output voltage and the minimum output voltage over the specified temperature range expressed as a percentage of 10 V:

$$\Delta V_{OT} = \left| \frac{V_{MAX} - V_{MIN}}{10\ V} \right| \times 100$$

[2] ΔV_{OT} specification applies trimmed to +10,000 V or untrimmed.
[3] TCV_O is defined as ΔVar divided by the temperature range; therefore,

$$TCV_O(0°C\ to + 70°C) = \frac{\Delta V_{OT}(0°C\ to + 70°C)}{70°C} \text{ and } TCV_O(-55°C\ to + 125°C) = \frac{\Delta V_{OT}(-55°C\ to + 125°C)}{180°C}$$

[4] Line and load regulation specifications include the effect of self-heating.

ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating[1]
Input Voltage	40 V
Output Short-Circuit Duration	
(to Ground or V_{IN})	Indefinite
Storage Temperature Range	
J, S, and Z Packages	−65°C to +150°C
P Package	−65°C to +125°C
Operating Temperature Range	
REF01A	−55°C to +125°C
REF01CJ	0°C to 70°C
REF01CP, REF01CS, REF01E, REF01H	−40°C to +85°C
Junction Temperature (T_J)	−65°C to +150°C
Lead Temperature (Soldering @ 60 sec)	300°C

[1] Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

Table 6.

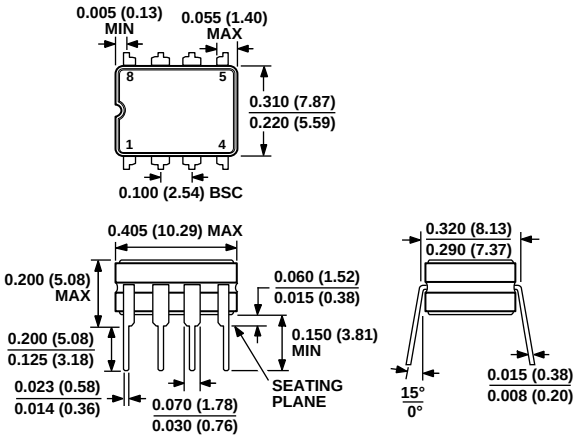
Package Type	θ_{JA}[1]	θ_{JC}	Unit
TO-99 (J)	170	24	°C/W
8-Lead CERDIP (Z)	162	26	°C/W
8-Lead PDIP (P)	110	50	°C/W
8-Pin SOIC (S)	160	44	°C/W

[1] θ_{JA} is specified for worst-case mounting conditions; that is, θ_{JA} is specified for device in socket for TO, CERDIP, and PDIP packages. θ_{JA} is specified for device soldered to printed circuit board for SOIC package.

ESD CAUTION

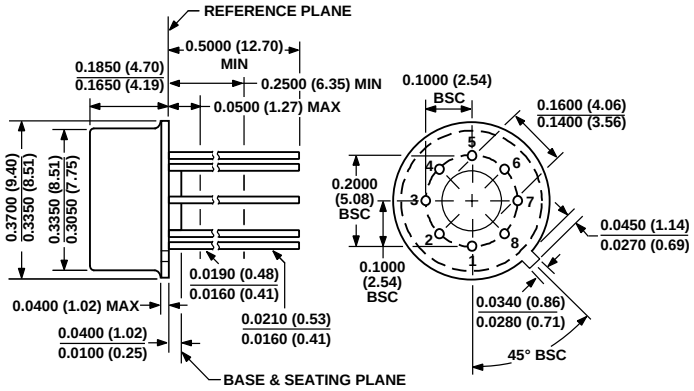
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

OUTLINE DIMENSIONS



CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 22. 8-Lead Ceramic Dual In-Line Package [CERDIP]
(Q-8)
Z-Suffix
Dimensions shown in inches and (millimeters)



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CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 23. 8-Lead Metal Header [TO-99]
(H-08)
J-Suffix
Dimensions shown in inches and (millimeters)

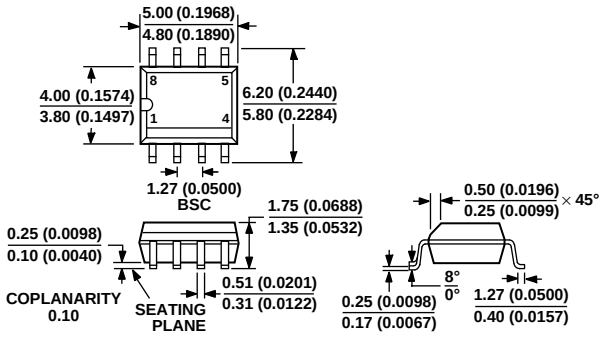

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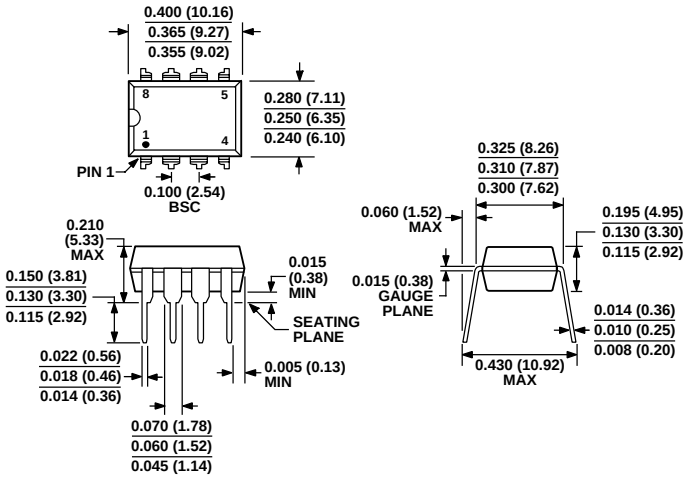
Figure 24. 8-Lead Standard Small Outline Package [SOIC]
Narrow Body
(R-8)
S-Suffix
Dimensions shown in millimeters and (inches



COMPLIANT TO JEDEC STANDARDS MS-001-BA
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 25. 8-Lead Plastic Dual In-Line Package [PDIP]
Narrow Body
(N-8)
P-Suffix
Dimensions shown in inches and (millimeters)

ORDERING GUIDE

Model	T_A = 25° C ΔV_{OS} Max (mV)	Temperature Range (°C)	Package Description[1]	Package Option
REF01AJ/883C	±30	−55 to +125	8-Lead TO-99	J-Suffix (H-08)
REF01EJ	±30	−40 to +85	8-Lead TO-99	J-Suffix (H-08)
REF01CJ	±100	0 to 70	8-Lead TO-99	J-Suffix (H-08)
REF01EZ	±30	−40 to +85	8-Lead CERDIP	Z-Suffix (Q-8)
REF01HZ	±50	−40 to +85	8-Lead CERDIP	Z-Suffix (Q-8)
REF01AZ/883C	±30	−55 to +125	8-Lead CERDIP	Z-Suffix (Q-8)
REF01CP	±100	−40 to +85	8-Lead PDIP	P-Suffix (N-8)
REF01CPZ[2]	±100	−40 to +85	8-Lead PDIP	P-Suffix (N-8)
REF01HPZ[2]	±50	−40 to +85	8-Lead PDIP	P-Suffix (N-8)
REF01HP	±50	−40 to +85	8-Lead PDIP	P-Suffix (N-8)
REF01HS[3]	±50	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01HS-REEL[3]	±50	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01HSZ[2, 3]	±50	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01HSZ-REEL[2, 3]	±50	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01CS[3]	±100	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01CS-REEL[3]	±100	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01CS-REEL7[3]	±100	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01CSZ-REEL[2, 3]	±100	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01CSZ-REEL7[2, 3]	±100	−40 to +85	8-Lead SOIC	S-Suffix (R-8)
REF01CSZ[2, 3]	±100	−40 to +85	8-Lead SOIC	S-Suffix (R-8)

[1] Burn-in is available on commercial and industrial temperature range parts in CERDIP, PDIP, and TO-99 packages.
[2] Z = Pb-free part.
[3] For availability and burn-in information on SOIC packages, contact your local Sales office.